

# SANYO Semiconductors DATA SHEET

# 2SJ655 — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- 4V drive.
- · Ultrahigh-speed switching.
- · Motor drive, DC / DC converter.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		-100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-12	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-48	Α
Allowable Power Dissipation	PD		2.0	W
	FD	Tc=25°C	25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1:4
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-100V, V <sub>GS</sub> =0			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> = ±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-6A	9	13		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =-6A, V <sub>G</sub> S=-10V		100	136	mΩ
	RDS(on)2	ID=-6A, VGS=-4V		136	190	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =-20V, f=1MHz		2090		pF
Output Capacitance	Coss	V <sub>DS</sub> =-20V, f=1MHz		155		pF
Reverse Transfer Capacitance	Crss	Vps=-20V, f=1MHz		108		pF

Marking: J655 Continued on next page.

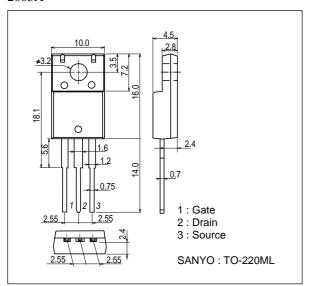
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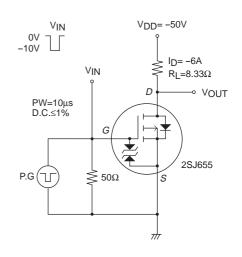
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		17		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		95		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		187		ns
Fall Time	tf	See specified Test Circuit.		95		ns
Total Gate Charge	Qg	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-12A		41		nC
Gate-to-Source Charge	Qgs	VDS=-50V, VGS=-10V, ID=-12A		7		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =-50V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-12A		9		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-12A, V <sub>GS</sub> =0		-0.88	-1.2	V

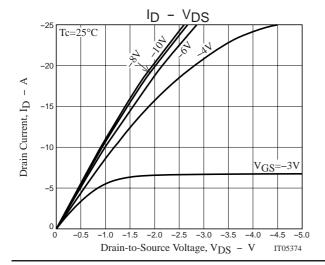
## **Package Dimensions**

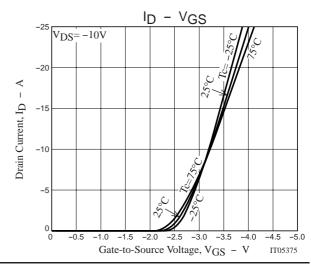
unit : mm 2063A

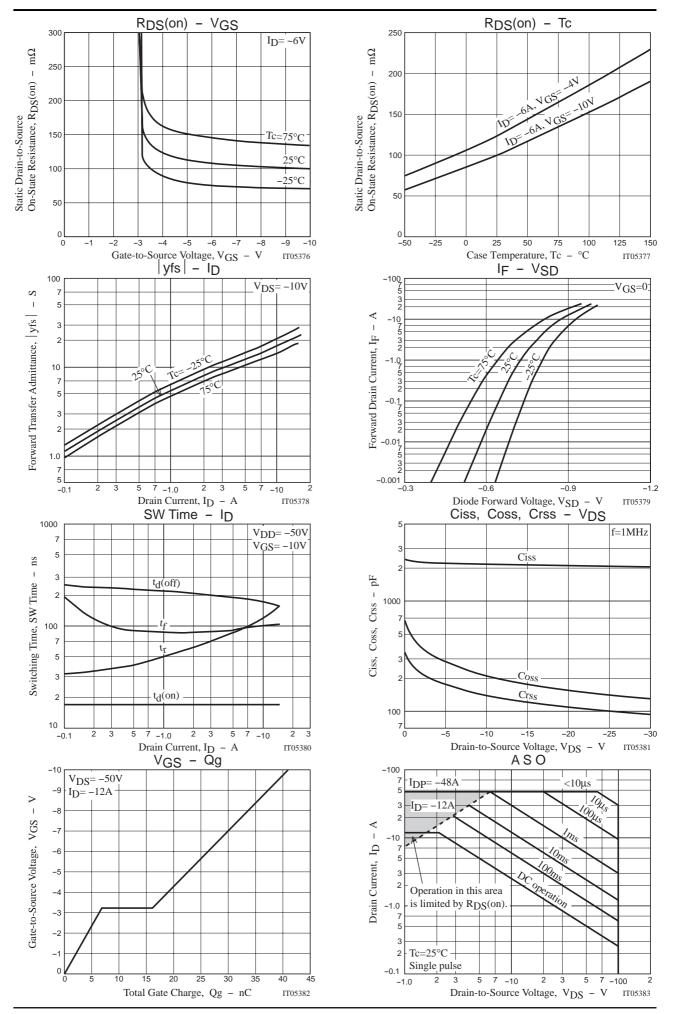


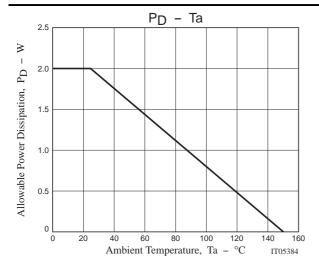
# **Switching Time Test Circuit**

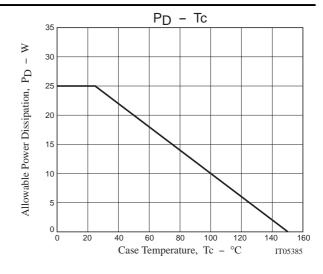












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